

# 1s2p resonant inelastic X-ray scattering combined dipole and quadrupole analysis method

Alexander Bagger,<sup>a,b,\*</sup> Ties Haarman,<sup>b,c</sup> Anna Puig Molina,<sup>b</sup> Poul George Moses,<sup>b</sup> Hirofumi Ishii,<sup>d</sup> Nozomu Hiraoka,<sup>d</sup> Yu-Han Wu,<sup>d</sup> Ku-Ding Tsuei,<sup>d</sup> Ib Chorkendorff<sup>a</sup> and Frank De Groot<sup>c</sup>

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<sup>a</sup>Department of Physics, Technical University of Denmark, DK-2800 Lyngby, Denmark, <sup>b</sup>Haldor Topsoe A/S, DK-2800 Lyngby, Denmark, <sup>c</sup>Department of Inorganic Chemistry and Catalysis, Debye Institute, University of Utrecht, Sorbonnelaan 16, 3584 CA Utrecht, The Netherlands, and <sup>d</sup>National Synchrotron Radiation Research Center, SPring-8, Japan. \*Correspondence e-mail: bagger.alexander@gmail.com

In this study an analysis strategy towards using the resonant inelastic X-ray scattering (RIXS) technique more effectively compared with X-ray absorption spectroscopy (XAS) is presented. In particular, the question of when RIXS brings extra information compared with XAS is addressed. To answer this question the RIXS plane is analysed using two models: (i) an exciton model and (ii) a continuum model. The continuum model describes the dipole pre-edge excitations while the exciton model describes the quadrupole excitations. Applying our approach to the experimental 1s2p RIXS planes of VO<sub>2</sub> and TiO<sub>2</sub>, it is shown that only in the case of quadrupole excitations being present is additional information gained by RIXS compared with XAS. Combining this knowledge with methods to calculate the dipole contribution in XAS measurements gives scientists the opportunity to plan more effective experiments.

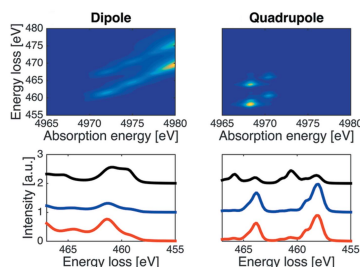
## 1. Introduction

Resonant inelastic X-ray scattering (RIXS) spectroscopy is an advanced synchrotron technique that combines X-ray absorption spectroscopy (XAS) and X-ray emission spectroscopy (XES). Thus, the RIXS technique is element-selective and measures both the unoccupied and occupied states together with their interference. Here one can probe magnetic and phonon modes (Ament *et al.*, 2011). Experimentally, the RIXS plane is collected by scanning an emission energy window at each absorption energy step through the *K*-, *L*- or *M*-edge regions, resulting in a two-dimensional RIXS plane. RIXS has proven successful in giving insight into bulk materials, nanoparticles and molecular metal complexes (Smolentsev *et al.*, 2011; Glatzel *et al.*, 2010; Garino *et al.*, 2012; De Groot & Kotani, 2008). However, there can be systems where RIXS does not bring additional information compared with XAS.

In this paper we address the question of when it is beneficial to measure 1s2p RIXS, where the 1s2p labels the *K*-edge excitation and the *K<sub>α</sub>* decay. As for all experimental techniques, the important point is not the measurement itself but how we obtain information from the experiment.

In the theory section, we present two known models for RIXS data analysis: (i) the exciton model, describing the excitation to an exciton state, and (ii) the continuum model, describing the excitation to a band state.

First we show for an arbitrary system how RIXS spectral features are generated with the continuum model. This will show the general XAS and XES convoluting origin of the



RIXS measurement. Next, the two models are applied to real RIXS data: the VO<sub>2</sub> (newly recorded) and TiO<sub>2</sub> systems. Finally, a methodical experimental RIXS approach is suggested based on the results.

## 2. Theory

The mathematical formulation of the RIXS process is described by the Kramers–Heisenberg equation, which is a second-order process. The Kramers–Heisenberg equation can be compared with the Golden Rule describing the XAS process. The Kramers–Heisenberg equation is formulated as (De Groot & Kotani, 2008)

$$\frac{d^2\sigma}{d\Omega d\omega} = r_0^2 \frac{\omega}{\Omega} \sum_j \left| \sum_i \frac{\langle j|T_2|i\rangle\langle i|T_1|g\rangle}{E_g + \hbar\Omega - E_i + i\Gamma_i} \right|^2 \times \delta(E_g + \hbar\Omega - E_j - \hbar\omega), \quad (1)$$

where  $\sigma$  is the scattering cross-section,  $r_0^2$  is the electron radius,  $\hbar\omega$  is the emission photon energy,  $\hbar\Omega$  is the absorption photon energy,  $T_1$  and  $T_2$  are the transition operators and  $\Gamma_i$  describes the lifetime broadening of the intermediate state. The labelling  $g$ ,  $i$  and  $j$  denotes the ground state, intermediate state and final state, respectively.  $E$  describes the energy of the  $|g\rangle$ ,  $\langle i|$ ,  $|i\rangle$  and  $\langle j|$  states including both photon and full electronic description. To calculate RIXS planes the equation is simplified, as follows:

(i) *In the exciton model*: the charge transfer multiplet (CTM) model applies the equation to a limited electronic system (Stavitski & de Groot, 2010). The approximations in this model can be listed as: (1) calculation of electron–electron interaction of an isolated atom in the Hartree–Fock approximation, which is scaled to atomic data, and includes the spin-orbit term; (2) local environment ligand charge fluctuations are included by a perturbing crystal field term and charge transfer excitations; and (3) transition energies are not calculated but tabulated values are used instead. This essentially means that for a  $K$ -edge calculation, within this framework, the calculation results in a local quadrupole transition calculation. In general, it must be noted that calculating the transition energies from first principles is difficult due to incorrect description of the core hole screening (Juhin *et al.*, 2010). The multiplet model has, among others, been successfully applied to describe hard X-ray RIXS features of Fe complexes (de Groot *et al.*, 2005) and CoO (Kurian *et al.*, 2013).

(ii) *In the continuum model*: instead of applying the Kramers–Heisenberg equation to electronic calculations, it was simplified with two approximations by Tulkii & Åberg (1982). The first approximation assumes one electron states and the second assumes that the intermediate and final states are orthogonal to each other, which results in the following equation:

$$\frac{d\sigma(\omega_1)}{d\omega_2} = k \int_{-\infty}^{\infty} \frac{\omega_2}{\omega_1} \frac{g_{2p,1s}(\Omega_{1s} - \omega)(dg_{1s}/d\omega)}{(\Omega_{1s} + \omega - \omega_1)^2 + \Gamma_{1s}^2/4\hbar^2} \times \delta(\omega_1 - \Omega_{2p} - \omega - \omega_2) d\omega, \quad (2)$$

where

$$k = 2\pi r_0^2 (\Omega_{1s} - \Omega_{2p}).$$

Here  $\omega_1$  and  $\omega_2$  are the variable absorption and emission energies, respectively, while  $\Omega_{1s}$  and  $\Omega_{2p}$  are the fixed energies of the  $K$ -edge and energy loss, respectively.  $g_{2p,1s}$  is the oscillator strength of the transition and  $\Gamma_{1s}$  is the lifetime broadening.  $dg_{1s}/d\omega$  is a variable oscillator strength depending on the density of unoccupied states probed in the  $1s$  excitation. The unoccupied states are shifted to 0 eV at the inflection point in the model and the  $\delta$  function represents the decay channel. In the case of  $1s2p$  RIXS the  $\delta$  function can be assumed to be Lorentzian, describing the  $K\alpha_1$  and  $K\alpha_2$  decay. For other RIXS experiments, with  $K_\beta$  or  $K_{\text{valence}}$  decay, the Lorentzian decay can be changed to a function of the density of occupied states. This simplified approach has been used to describe hard X-ray RIXS features in CuO (Hayashi *et al.*, 2002), LiF (Kikas *et al.*, 2004) and KMnO<sub>4</sub> (Tulkii & Åberg, 1982).

## 3. Simple model

The continuum model equation (2) was applied to an arbitrary system, with an excitation energy at 2000 eV and a decay energy of 1000 eV, to illustrate how the convolution in the model effects the decay spectra. Three intuitive cases were explored: (i) a single excitation, (ii) a square continuum excitation and (iii) a square continuum and an excitation state below the continuum (pre-peak). The RIXS decay spectra, together with the density of unoccupied states (DOS), are shown in Fig. 1. The RIXS decay spectra change by applying different DOS. When the excitation energy is tuned below 2000 eV, the spectral intensity drops and, depending on the shape of the DOS, the decay spectra appear distorted. For the model of interest, with a state below the continuum, the decay spectra are strong when tuning the excitation energy to the pre-peak energy. Further, at very low excitation energy the inverted DOS appears, which is applied in the high-energy-resolution off-resonant spectroscopy (HEROS) technique (Szlachetko *et al.*, 2012).

## 4. Example: vanadium oxide

Vanadium oxide in the VO<sub>2</sub> form has attracted much attention both experimentally (Morin, 1959; Abbate *et al.*, 1991; Shin *et al.*, 1990) and theoretically (Korotin *et al.*, 2002; Liebsch *et al.*, 2002; Haverkort *et al.*, 2005; Yuan *et al.*, 2012; Gatti *et al.*, 2007; Sakuma *et al.*, 2008) due to its metal–insulator transition (MIT) at 67°C. At room temperature, as in our experiments, the VO<sub>2</sub> structure is in the insulating monoclinic phase (M<sub>1</sub>) with an experimental band gap of 0.6 eV (Shin *et al.*, 1990).

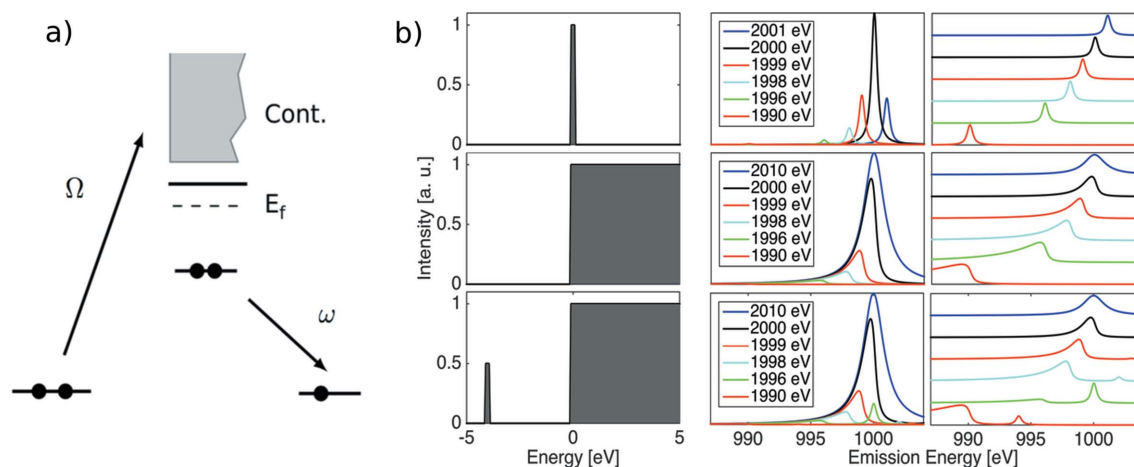


Figure 1

(a) Energy diagram of the RIXS measurement, with  $\Omega$  as the excitation photon and  $\omega$  as the decay photon.  $E_f$  and Cont. denote the Fermi level and the continuum of states, respectively. (b) The continuum model (2) applied to a 2000 eV excitation and 1000 eV decay system. Left: three different density of unoccupied states used as input for the model. Middle: RIXS decay spectra as output from the model at different excitation energies. Right: similar to the middle spectra, but normalized to show all features.

In this experiment the  $1s2p$  RIXS data of  $\text{VO}_2$  were recorded at the BL12XU beamline at SPring-8, Japan. The incident beam was selected by a double-crystal monochromator to a energy bandwidth of less than 1.0 eV at 5480 eV. The sample was oriented by  $45^\circ$  relative to the incident beam. The backscattered fluorescence signal, led through a helium-filled box, was analysed by a silicon (400) crystal. The sample used was a 99.9% pure Sigma-Aldrich (CAS #12036-21-4)  $\text{VO}_2$  powder. The experiments were performed at room temperature and with the sample in a nitrogen gas environment to prevent oxidation.

First the  $K$ -edge XAS of the sample was measured. This was performed by scanning from 40 eV above the 5480 eV edge to 40 eV below. The XAS spectrum is seen in Fig. 2(a). The XAS has been normalized to the incoming photon flux to correct for fluctuations in the synchrotron beam and the background has been subtracted. Further, to apply the XAS as empty DOS in the continuum model, the intensity has been set to 0 at  $-5464$  eV, to remove some of the broadening from the experimental XAS, and last the measured edge value has been extended.

The XAS spectrum shows a pre-peak at 5470 eV, which as a first approximation can be assigned to a  $1s \rightarrow 3d$  transition (quadrupole transition), while the main edge is a  $1s \rightarrow p$ -band transition (dipole selection rule). In the  $1s2p$  RIXS experiment the emission spectra are measured at specific excitation energies in the pre-peak region (see Fig. 2d). The RIXS plane shows from

left to right the pre-peak and parts of the main edge. In the emission energy the spin-orbit term splits the decay channels into the  $K\alpha_1$  and  $K\alpha_2$  decays.

Fig. 2(b) shows the simulated RIXS plane by the continuum model. In this simulation, the RIXS plane is obtained by using the XAS spectra of the  $\text{VO}_2$  sample as a first approximation for the density of unoccupied states and convoluting it with the Lorentzian  $K\alpha_1$  and  $K\alpha_2$  decay channels (originating from spin orbit splitting). The broadening factors were chosen to be  $\Gamma_{1s} = 1.5$  eV and  $\Gamma_{2p} = 0.5$  eV. In Fig. 2(c) a comparison of

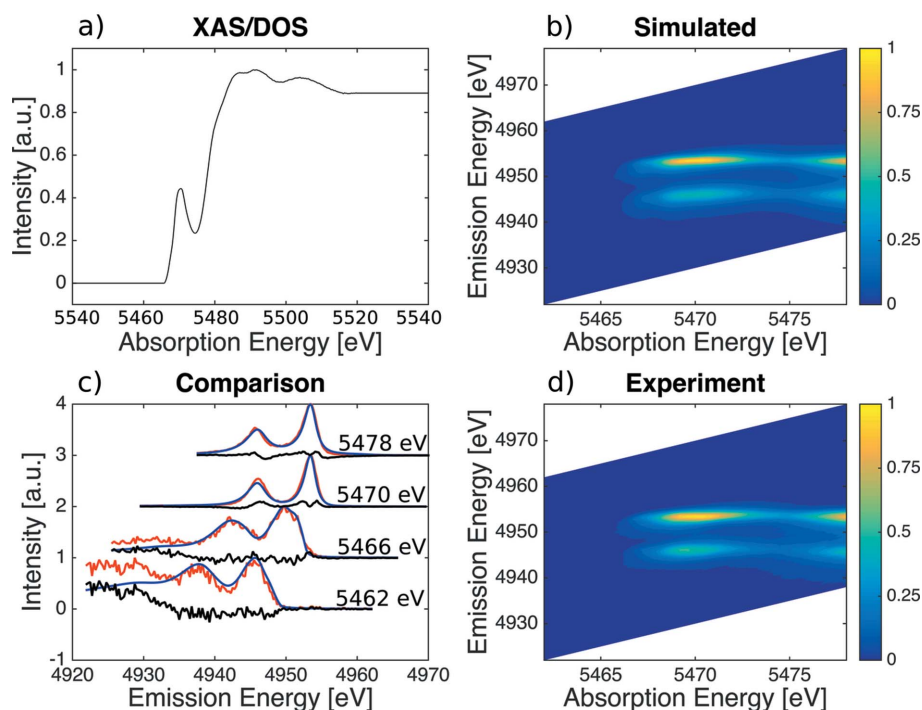
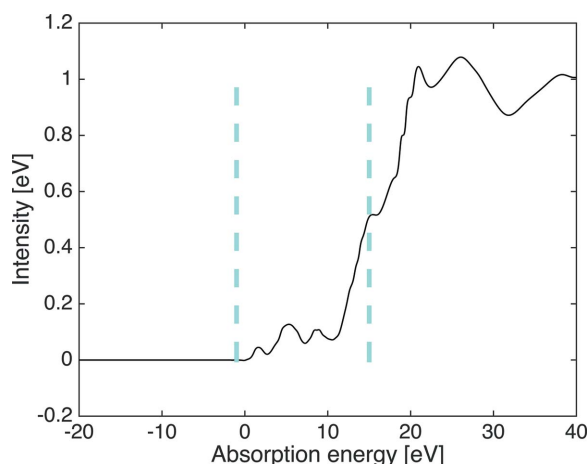


Figure 2

The continuum model applied to the  $\text{VO}_2$  RIXS experiment. (a) The XAS is used as DOS input for the model. (b) The simulated and (d) experimental RIXS plane. (c) Comparison of selected RIXS slices of the simulation (blue), experiment (red) and difference (black).



**Figure 3**  
XAS of anatase  $\text{TiO}_2$ . The three pre-peak features are labelled  $A_1$ ,  $A_2$  and  $A_3$ , where  $A_1$  is pure quadrupole and  $A_2$  and  $A_3$  are dipole. The region of interest for RIXS is within the two dashed lines.

four selected spectra are shown, with the simulation (blue), experiment (red) and difference (black). The blue simulation successfully fits the experiment in this case, both at the edge (5478 eV), in the center of the pre-peak (5470 eV) and at the lower two more distorted RIXS spectra (5462 eV and 5466 eV).

## 5. Example: titanium oxide

$\text{TiO}_2$  anatase is interesting for investigation because it has three pre-peak features with both quadrupole and dipole origin (see Fig. 3). The three pre-peak features have been analysed and labelled by Cabaret *et al.* (1999). The first pre-peak,  $A_1$ , is pure quadrupole. The second pre-peak,  $A_2$ , is mainly dipole; however, depending on orientation it has a

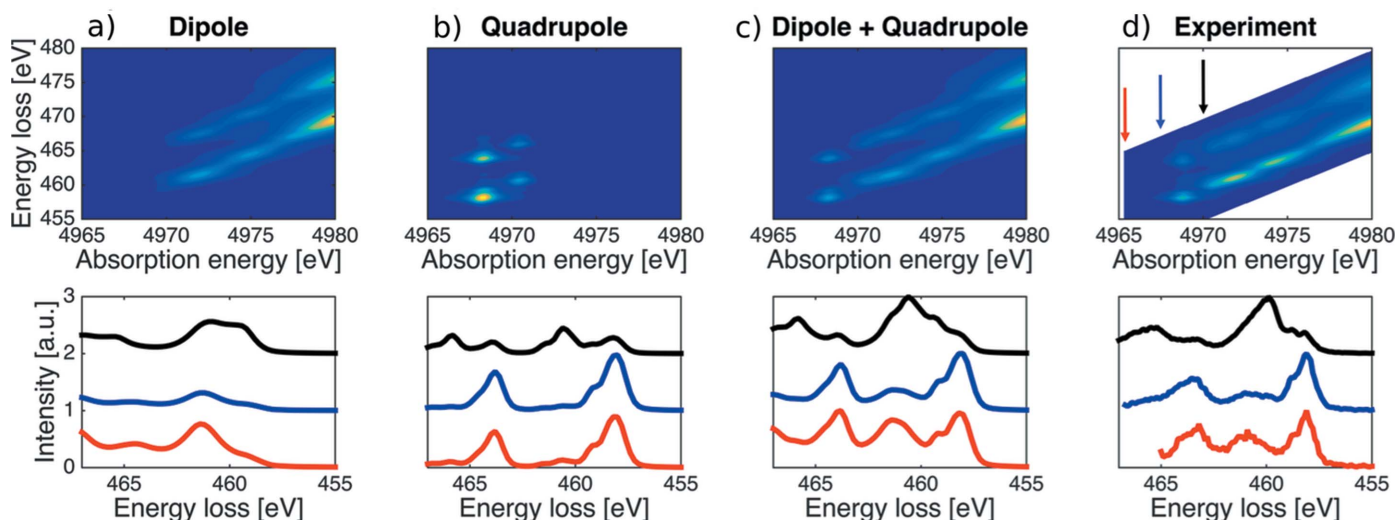
small quadrupole contribution. The last pre-peak,  $A_3$ , is a dipole contribution.

In our analysis we want to show how the dipole contribution is simulated by the continuum model and the  $A_1$ , quadrupole, pre-peak is calculated by the exciton model. We therefore import the dipole calculated XAS from Cabaret *et al.* (1999) and apply it to our simulation, similar to the  $\text{VO}_2$  example.

Fig. 4(a) shows the dipole RIXS plane and Fig. 4(b) shows the quadrupole RIXS plane. The dipole RIXS plane is simulated by the continuum model *via* the dipole XAS spectrum. The quadrupole RIXS plane is calculated with the exciton model, using the parameters extracted from the XPS work by Okada & Kotani (1993) [*i.e.*  $\Delta = 4$  eV,  $U = 4$  eV,  $Q = 6$  eV,  $T(\text{eg}) = 3$  eV,  $T(\text{t}2\text{g}) = 1.5$  eV and  $10\text{Dq}(\text{ion}) = 1.7$  eV]. For both dipole and quadrupole analysis, we apply the same broadening factors as for the  $\text{VO}_2$  simulation.

In Fig. 4(c) the dipole simulated and quadrupole calculated RIXS plane are added together. Finally, Fig. 4(d) shows the experimental  $1s2p$   $\text{TiO}_2$  RIXS plane [data courtesy of Glatzel *et al.* (Kas *et al.*, 2011; Glatzel *et al.*, 2013)]. In the bottom row for each RIXS plane three selected emission spectra are shown: 4965 eV (red), 4967 eV (blue) and 4970 eV (black).

The combined RIXS plane and the three selected RIXS spectra in the bottom row are identical to the experimental RIXS result. This is also illustrated in Fig. 5, where a direct comparison of the experimental and simulated RIXS spectra has been carried out. We do not show a difference curve, as in X-ray diffraction data or alike, because this requires a fitting of both broadening factors and possible energy shifts. Here it is seen that peak position and shape compare nicely with experimental data. This is a strong indication that the methodology of calculating the dipole and quadrupole RIXS planes separately is a good approach. Furthermore, in this method, each peak can be assigned to quadrupole or dipole origin. In the RIXS spectra at 4965 eV (red), the central peak is a dipole



**Figure 4**  
(a) Dipole simulation, (b) quadrupole calculation, (c) combined dipole and quadrupole RIXS plane and (d) experimental RIXS data. The top row shows the RIXS planes, while the bottom row shows selected RIXS spectra: 4965 eV (red), 4967 eV (blue) and 4970 eV (black). The origins of the selected are marked with matching arrows in the experimental RIXS data (d). In this case we have chosen to show data on the energy-loss axis, which is simply calculated by subtracting the emission energy from the absorption energy.

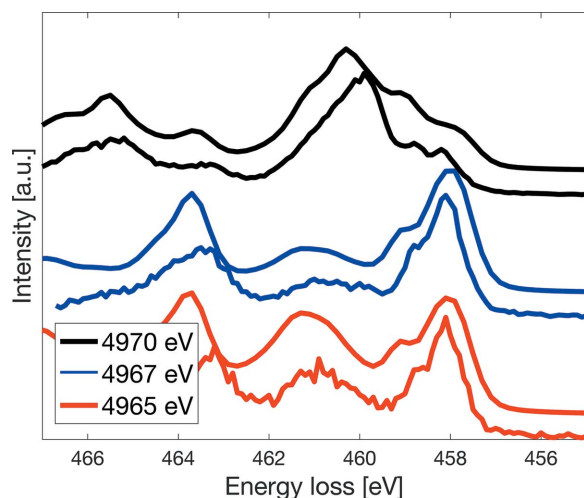


Figure 5

Direct comparison between RIXS spectra 4965 eV (red), 4967 eV (blue) and 4970 eV (black) from Figs. 4(c) and 4(d) bottom. The simulation is placed just above the experimental spectra.

peak from the continuum model, while the left and right peaks with shoulder features are quadrupoles. Also we identify the quadrupole double peak on the diagonal of the pure quadrupole RIXS plane as found by Cabaret *et al.* (1999).

## 6. Discussion

In the previous two sections we have displayed how the VO<sub>2</sub> experimental RIXS plane can be simulated entirely by the continuum model. Furthermore, the continuum model describes the two dipole peaks of the TiO<sub>2</sub> anatase RIXS experiment. However, the quadrupole pre-peak of TiO<sub>2</sub> requires the exciton model to be explained.

In the continuum model a single electron excitation approximation is applied, which means that the model describes excitations to band-like unoccupied states. Compared with the difficulties of describing the correct band structure of the MIT of VO<sub>2</sub> it is quite remarkable that at the current resolution of less than 1.0 eV the continuum model actually achieves this good description with the current experimental resolution.

In particular, in the case of exciting to band-like states, it must be realised that it is not necessary to measure the RIXS plane explicitly as it can be generated by the convolution of the XAS and the XES (Rubensson, 2000).

If an already known analysis of the XAS pre-peak region exists, as in the case of TiO<sub>2</sub> by Cabaret *et al.* (1999) or the VOPO<sub>4</sub>·2H<sub>2</sub>O analysis by Poumellec *et al.* (1998), then, beforehand, the area of interest can be defined and measured by RIXS. However, if the pre-peak region is unknown, we suggest, for pure systems, the following steps:

- (i) Measure the XAS and XES spectra, and create the two-dimensional RIXS plane by the convolution of the XAS and XES spectra.
- (ii) Measure some RIXS slices. Note that if the RIXS spectra are equal to the convolution, one cannot achieve further insight from RIXS experiments.

(iii) If the RIXS slices deviate from the convolution, this quadrupole RIXS pre-edge region should be measured in a RIXS experiment and at a high resolution.

In the case of mixed systems it could still be beneficial to measure selected parts of the two-dimensional RIXS planes, to increase the accuracy in distinguishing different phases/valences/etc. Additionally, we believe that, in time, with increased resolution, exciton features will appear for all *d* and *f* systems as seen for the CoO RIXS investigation by Kurian *et al.* (2013).

In this paper we only investigated 1s2p RIXS of high valence compounds and it is interesting to think about how the methodology is extended to experiments other than 1s2p RIXS. For *L*<sub>2,3</sub> RIXS the decay may not be a simple Lorentzian decay as currently applied in the continuum model. Instead, the Lorentzian can be replaced by the density of occupied states (Smolentsev *et al.*, 2011). Another important point is that, with poor resolution, every RIXS spectrum can be described with the convolution model. In other words, one needs an excitonic effect that is larger than the experimental resolution in order to become visible. This may limit the usage of the convolution model with the present resolution of soft X-ray beamlines ranging from 20 to 200 meV for most systems.

## 7. Conclusion

In this work we have presented and applied two models for analysing RIXS data: (i) the exciton model and (ii) the continuum model. We have shown how RIXS features of dipole origin can be simulated by a convolution of the XAS and XES spectra (continuum model). Additionally, we have shown that the continuum model can describe all features of 1s2p VO<sub>2</sub> experimental RIXS plane. Furthermore, the analysis of the TiO<sub>2</sub> RIXS plane, with a combination of the continuum and exciton models, shows that only quadrupole RIXS peaks are relevant for RIXS measurements, while for dipole peaks a XAS experiment will be sufficient.

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